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		APPLICANT: Kevin E. Brehmer			
		GROUP ART UNIT: 2612		EXAMINER: Justin P. Misleh	
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Examiner's Initials	Cite No.	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication or of issue of Cited Document MM-DD-YYYY
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OTHER ART — NON PATENT LITERATURE DOCUMENTS

Examiner's Initials	Cite No	Include name of the author (in CAPITAL LETTERS) title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, relevant page(s), volume-issue number(s), publisher, city and/or country where published.	Translation (Y/N)
JM		CHAMBERLAIN, S.G., "Photosensitivity and Scanning of Silicon Image Detector Arrays," IEEE Journal of Solid-State Circuits, December 1969, pgs. 333-342	
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EXAMINER	/Justin Misleh/	DATE CONSIDERED	08/22/2006
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